## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Jack Hwang et al.

Group Art Unit:

2813

Serial No.:

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Examiner:

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For:

FORMING STRAINED

SOURCE DRAIN JUNCTION FIELD EFFECT TRANSISTORS

8888

Box Patent Application Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

## PRELIMINARY AMENDMENT

Sir:

Please amend the above-referenced application in accordance with the following SPECIFICATION AMENDMENTS and CLAIM AMENDMENTS sections.

Express Mail No.:	EL 337933193 US
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Date: August 20, 2003